General purpose transistor (isolated transistors)

EMD28

DTB543X \square and DTC144E \square A are housed independently in a EMT6 package.

Applications

DC / DC converter Motor driver

● Features

1) DTr₁: PNP digital transistor DTr₂: NPN digital transistor

2) Mounting possible with EMT3 automatic mounting

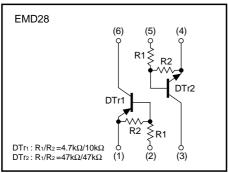
machines.

Structure

PNP / NPN Silicon epitaxial planar digital transistor

The following characteristics apply to both DTr1 and DTr2.

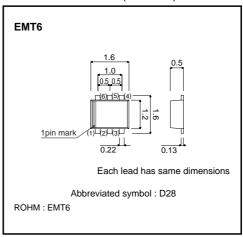
●Equivalent circuit



Packaging specifications

Type	EMD28
Package	EMT6
Marking	D28
Code	T2R
Basic ordering unit (pieces)	8000

●External dimensions (Unit: mm)



●Absolute maximum ratings (Ta=25°C)

DTr1

Parameter	Symbol	DTr1	Unit
Supply voltage	Vcc	-12	V
Input voltage	Vin	-12 to +7	V
Output current	Ic (MAX.)	-500	mA
Power dissipation	Pd	120	mW *
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

^{*} Each terminal mounted on a recommended.

DTr2

Parameter	Symbol	DTr2	Unit	
Supply voltage	Vcc	50	V	
Input voltage	Vin	V _{IN} -10 to +40		
Output current	lo	30	mA	
Output current	Ic (MAX.)	100	IIIA	
Power dissipation	Pd	120	mW *	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

^{*} Each terminal mounted on a recommended.

DTr1/Tr2

Parameter	Symbol	Limits	Unit
Power dissipation	Pd	150(TOTAL)	mW *
Storage temperature	Tstg	-55 to +125	°C

^{*} Each terminal mounted on a recommended.

●Electrical characteristics (Ta=25°C) DTr1

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input voltage	VI(off)	_	_	-0.3	V	Vcc= -5V / Io= -100uA
	VI(on)	-2.5	_	_	V	Vo= -0.3V / Io= -20mA
Output voltage	Vo(on)	_	-70	-300	mV	lo= −100mA, l= −5mA
Input current	lı	-	-	-1.8	mA	Vi= −5V
Output current	IO(off)	_	_	-0.5	μΑ	Vcc= -12V / Vi=0V
DC current gain	Gı	140	_	_	_	Vo= -2V / Io= -100mA
Transition frequency *	f⊤	_	260	_	MHz	Vc=-10V / Ie=5mA, f=100MHz
Input resistance	R ₁	3.29	4.7	6.11	kΩ	_
Resistance ratio	R ₂ /R ₁	1.7	2.1	2.6	_	-

^{*} Characteristics of built-in transistor.

DTr2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
lanut voltogo	VI(off)	_	_	0.5	V	Vcc=5V / Io=100uA
Input voltage	VI(on)	3	_	_	V	Vo=0.3V / Io=2mA
Output voltage	Vo(on)	_	100	300	mV	lo=10mA, l≔0.5mA
Input current	lı	_	_	0.18	mA	Vi=5V
Output current	IO(off)	_	_	0.5	μΑ	Vcc=50V / V⊫0V
DC current gain	Gı	68	_	_	-	Vo=5V / Io=5mA
Transition frequency *	f⊤	_	250	_	MHz	Vce=10V / Ie= -5mA, f=100MHz
Input resistance	R ₁	32.9	47	61.1	kΩ	-
Resistance ratio	R2/R1	0.8	1	1.2	_	_

^{*} Characteristics of built-in transistor.

Fig.6 DC current gain vs. output curren

•Electrical characteristic curves

DTr1

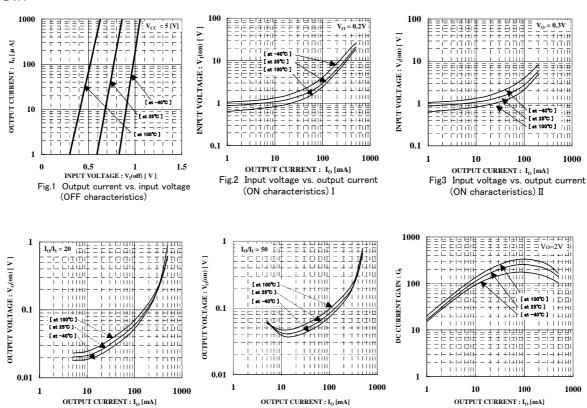


Fig.4 Output voltage vs. output current $\,I\,$ Fig.5 Output voltage vs. output current $\,I\!I\,$

DTr2

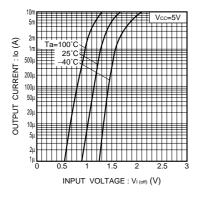


Fig.7 Output current vs. input voltage (OFF characteristics)

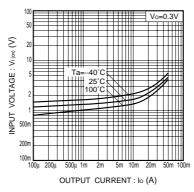


Fig.8 Input voltage vs. output current (ON characteristics)

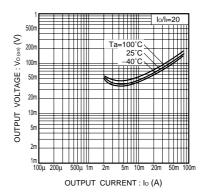


Fig.9 Output voltage vs. output

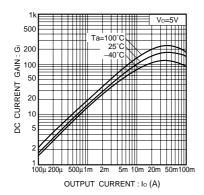


Fig.10 DC current gain vs. output current

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